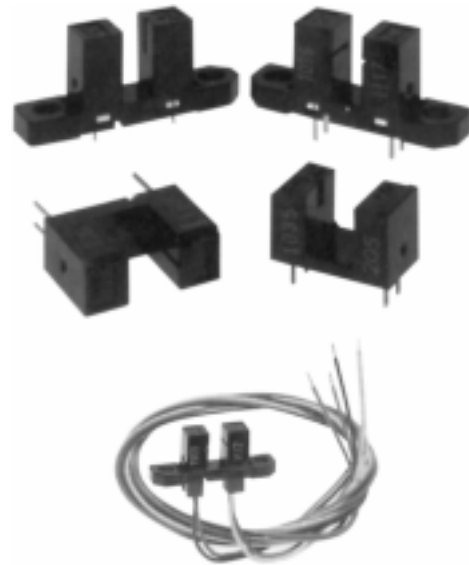


EE-SX1035/1081/1088(-W1)/1096(-W1)

Low-cost, PCB-mount with
Phototransistor Output

- LED and phototransistor assure long life and high reliability
- Non-contact, noiseless sensing, ideal for office automation and computer peripheral equipment
- Models available with either horizontal (EE-SX1096) or vertical (EE-SX1081/1088) aperture
- EE-SX1088(-W1) and EE-SX1096(-W1) wire harness versions provide easy, reliable solder-free connection



Ordering Information

Appearance	Sensing method	Slot width	Slot depth	Sensing object	Output configuration	Weight	Part number
	Transmissive	5.2 mm	5.4 mm	Opaque, 1.0 x 1.0 mm min.	Phototransistor	Approx. 1.3 g	EE-SX1035
		5.0 mm	7.5 mm	Opaque, 0.5 x 2.1 mm min.		Approx. 0.5 g	EE-SX1081
		3.4 mm	7.5 mm	Opaque, 2.1 x 0.5 mm min.		Approx. 0.6 g	EE-SX1088
				Opaque, 0.5 x 2.1 mm min.		Approx. 0.6 g	EE-SX1096
				Opaque, 2.1 x 0.5 mm min.	Phototransistor with wire harness	Approx. 4.5 g	EE-SX1088-W1
				Opaque, 0.5 x 2.1 mm min.		Approx. 4.5 g	EE-SX1096-W1

Specifications

■ ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}\text{C}$ (77°F))

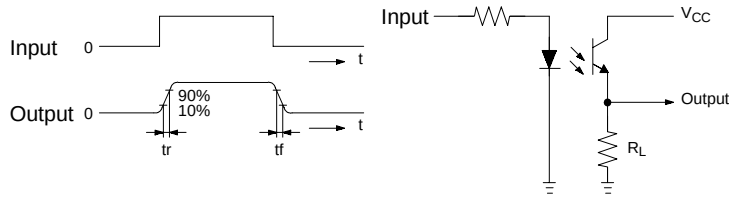
Item		Symbol	Rated value
Emitter	Forward current	I_F	50 mA*
	Reverse voltage	V_R	4 V
Detector	Collector-emitter voltage	V_{CEO}	30 V
	Collector current	I_C	20 mA
	Collector dissipation	P_C	100 mW*
Ambient temperature	Operating	T_{opr}	-25°C to 85°C (-13°F to 185°F)
	Storage	T_{stg}	-30°C to 100°C (-22°F to 212°F)

*Refer to Engineering Data if the ambient temperature is not within the normal room temperature range.

■ CHARACTERISTICS ($T_A = 25^{\circ}\text{C}$ (77°F))

Item		Symbol	Value	Condition
Emitter	Forward voltage	V_F	1.2 V typ.; 1.5 V max.	$I_F=30\text{mA}$
	Reverse current	I_R	0.01 μA typ.; 10 μA max.	$V_R=4\text{ V}$
	Peak emission wavelength	$\lambda_p(L)$	940 nm	$I_F=20\text{ mA}$
Detector	Dark current	I_D	2 nA typ.; 200 nA max.	$V_{CE}=10\text{ V } 0\text{ lx}$
	Peak spectral sensitivity wavelength	$\lambda_p(P)$	850 nm typ.	$V_{CE}=10\text{ V}$
Combination	Light current (collector current)	I_L	0.5 to 14 mA	$I_F=20\text{ mA}$ $V_{CE}=10\text{ V}$
	Collector-emitter saturated voltage	$V_{CE}(\text{sat})$	0.1 V typ.; 0.4 V max.	$I_F=20\text{ mA}$ $I_L=0.1\text{ mA}$
	Rising time*	t_r	4 μs typ.	$V_{CC}=5\text{ V}$ $I_L=5\text{ mA}$
	Falling time*	t_f	4 μs typ.	$R_L=100\ \Omega$

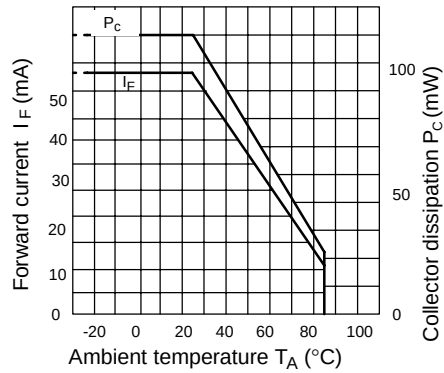
*The following illustrations show the rising time, t_r , and the falling time, t_f .



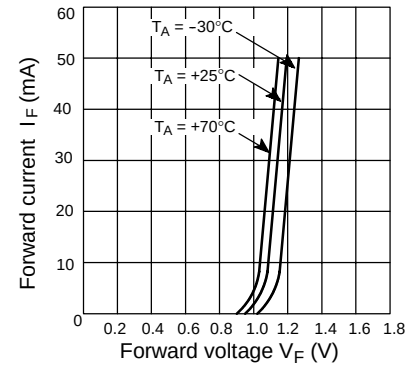
Engineering Data

Note: The operating conditions of the photomicrosensor must be within the absolute maximum rating ranges.

■ TEMPERATURE CHARACTERISTICS

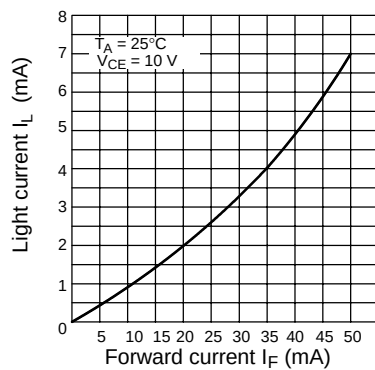


■ INPUT CHARACTERISTICS (TYPICAL)

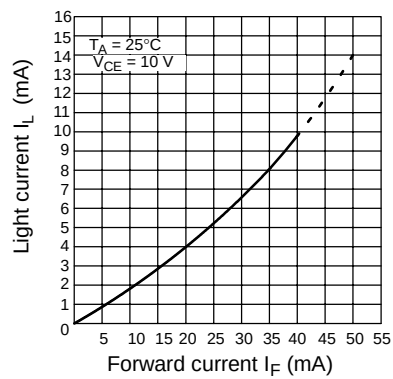


■ INPUT/OUTPUT CHARACTERISTICS (TYPICAL)

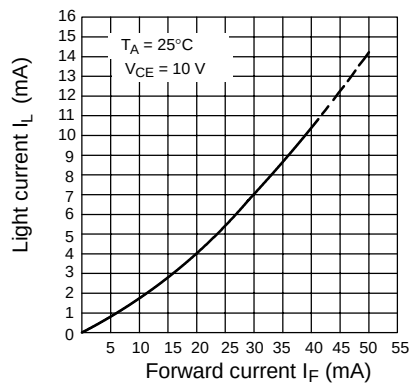
EE-SX1035



EE-SX1081

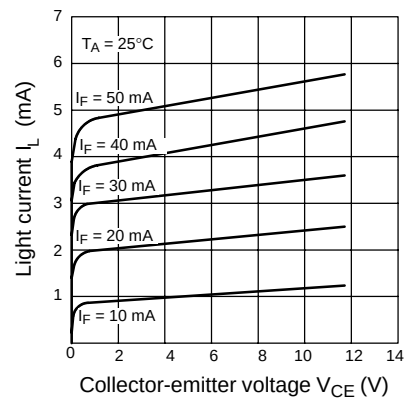


EE-SX1088/1096(-W1)

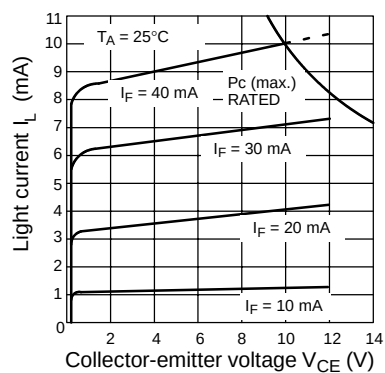


■ OUTPUT CHARACTERISTICS (TYPICAL)

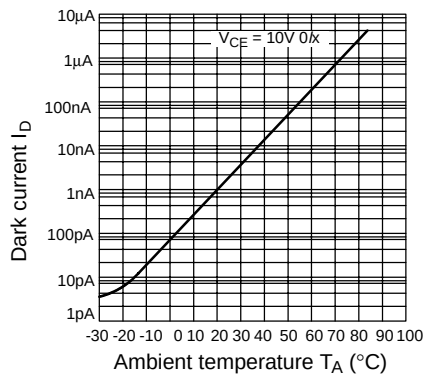
EE-SX1035



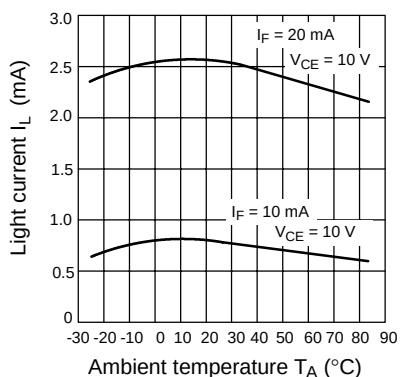
EE-SX1081/1088/1096(-W1)



■ DARK CURRENT TEMPERATURE DEPENDENCY (TYPICAL)

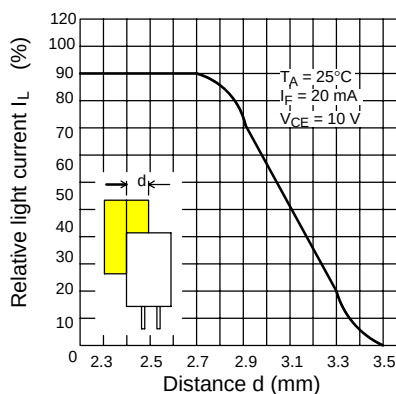


■ LIGHT CURRENT TEMPERATURE DEPENDENCY (TYPICAL)

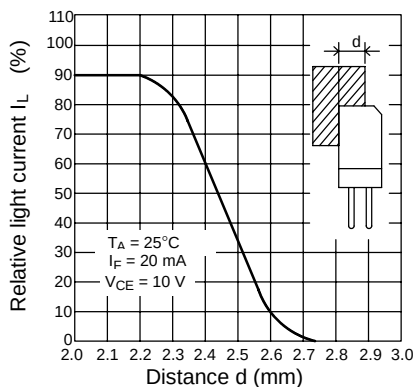


■ SENSING POSITION CHARACTERISTICS (TYPICAL)

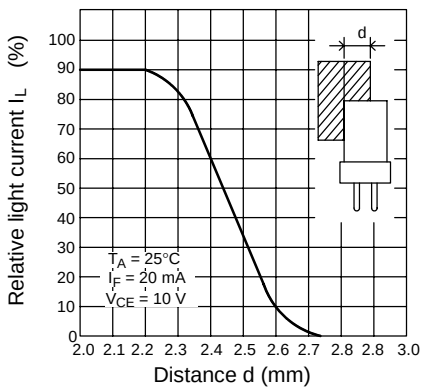
EE-SX1035



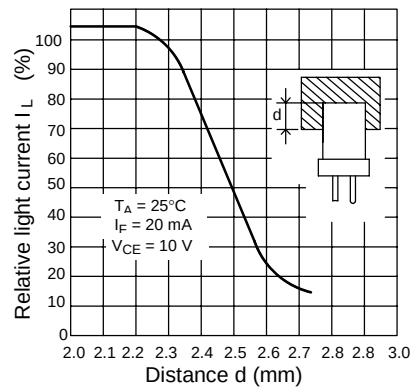
EE-SX1081



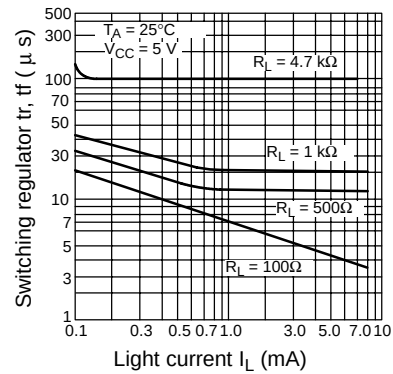
EE-SX1088(-W1)



EE-SX1096(-W1)



SWITCHING CHARACTERISTICS (TYPICAL)

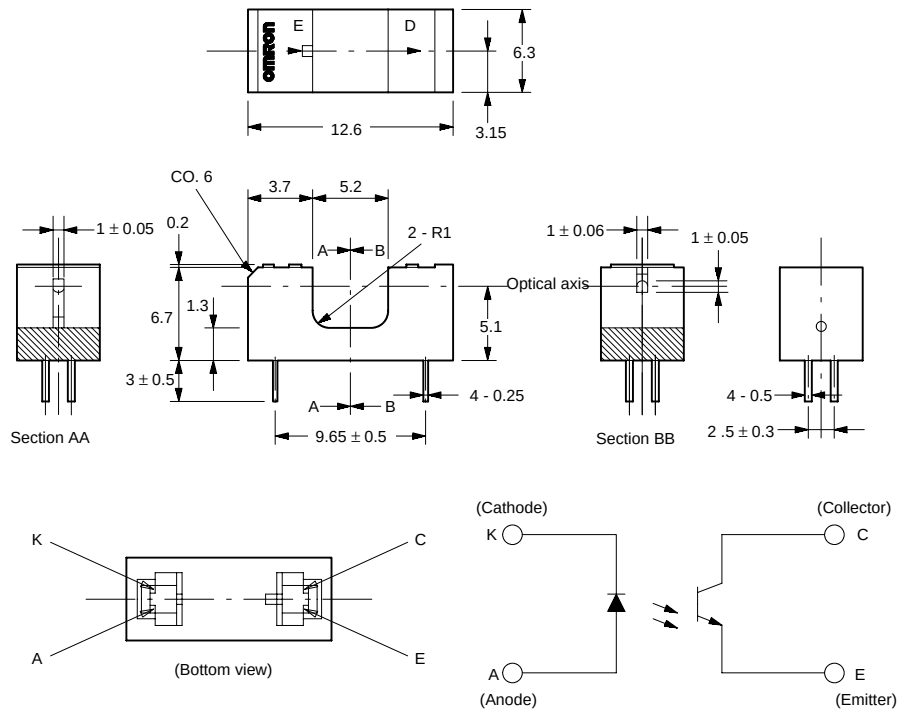
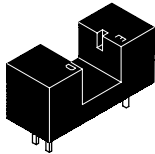


The t_r and t_f are almost the same in length.

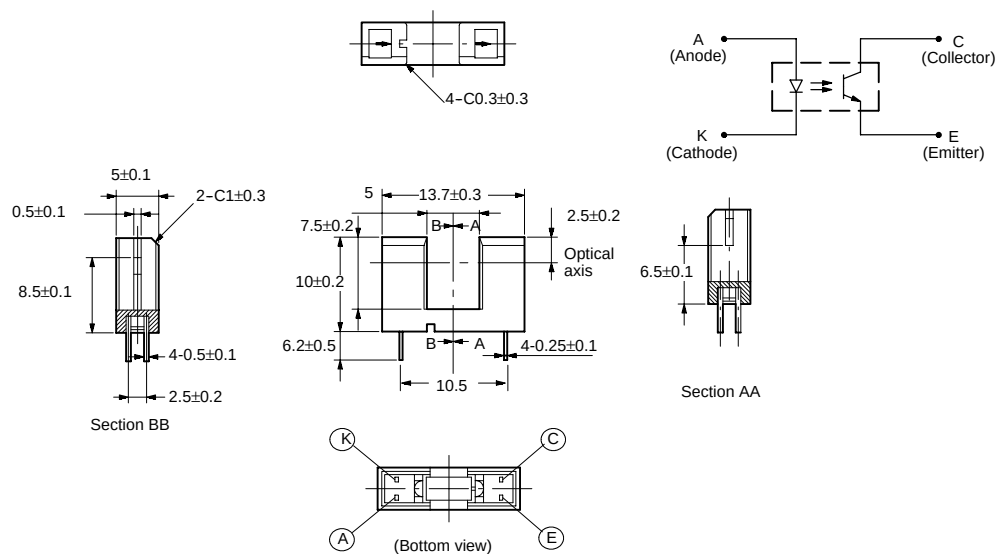
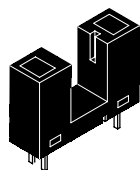
Dimensions

Unit: mm (inch)

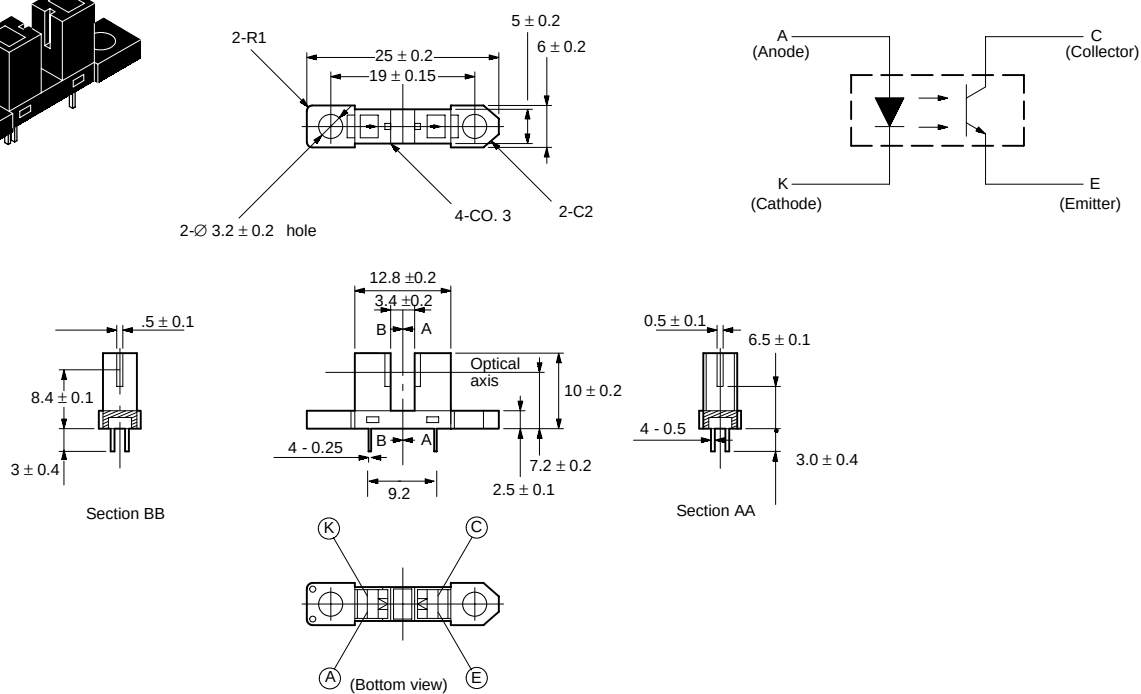
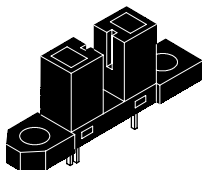
EE-SX1035



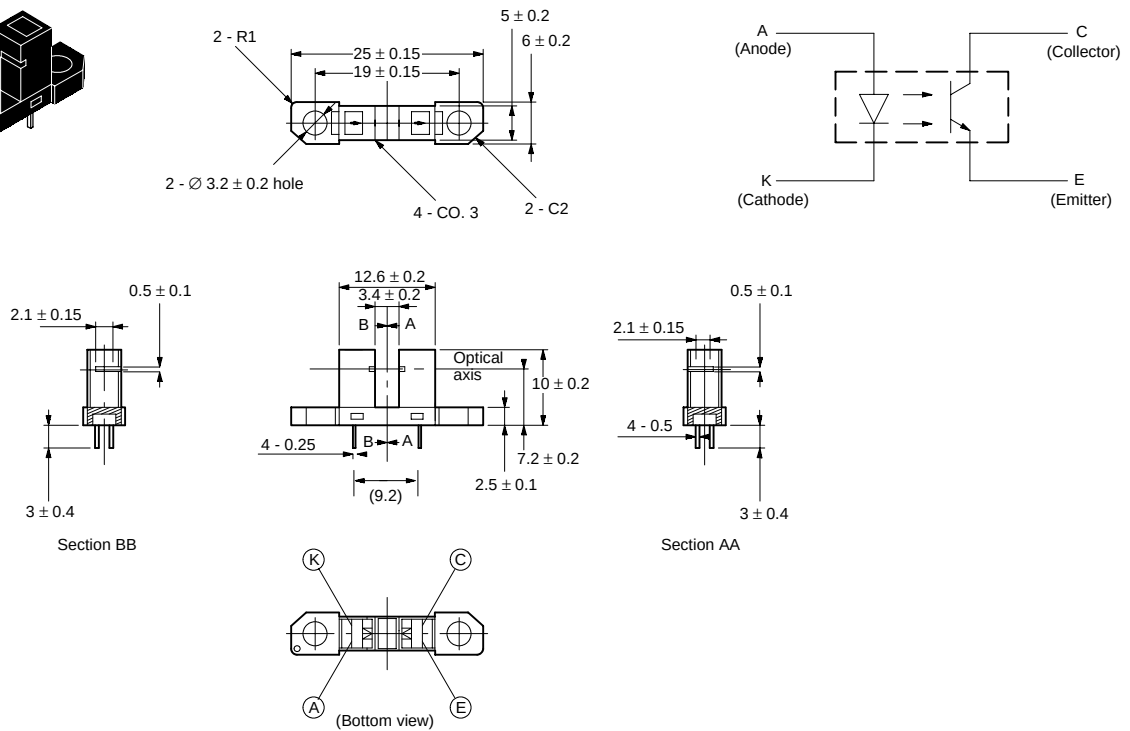
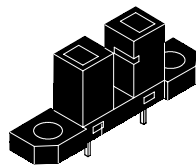
■ EE-SX1081



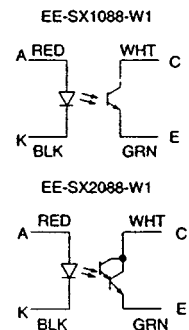
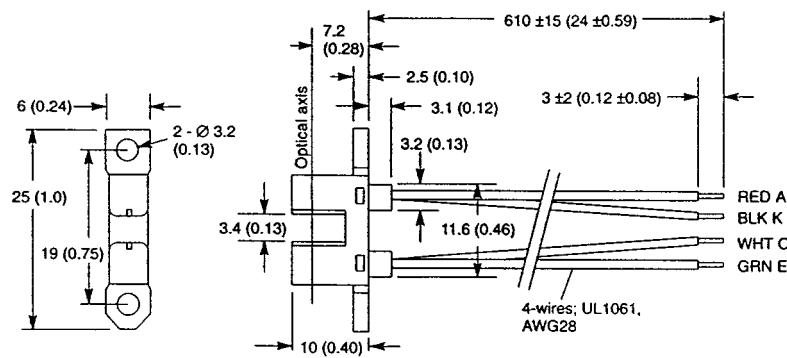
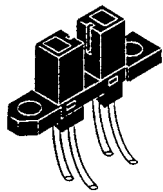
■ EE-SX1088



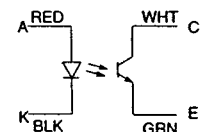
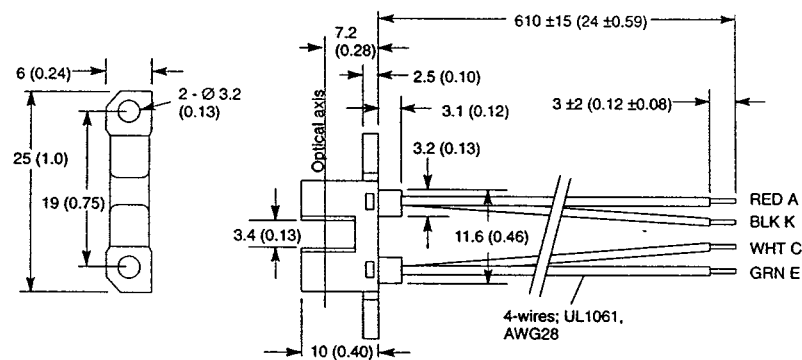
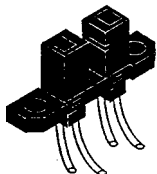
■ EE-SX1096



■ EE-SX1088-W1



■ EE-SX1096-W1



Precautions

Refer to the Technical Information Section for general precautions.

NOTE: DIMENSIONS SHOWN ARE IN MILLIMETERS. To convert millimeters to inches divide by 25.4.

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